

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IPI60R250CP

• FEATURES

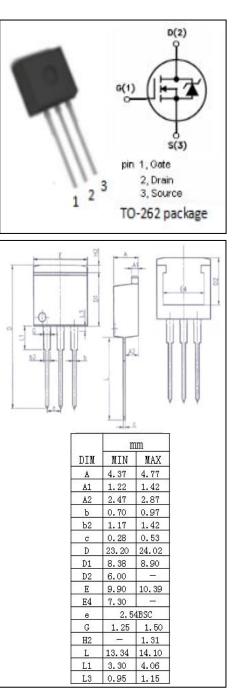
- Static drain-source on-resistance: R⊳s(on) ≤0.25Ω
- Enhancement mode
- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

- Ultra low gate charge
- High peak current capability

ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Drain-Source Voltage	600	V				
V _{GS}	Gate-Source Voltage	±20	V				
ID	Drain Current-Continuous	12	A				
I _{DM}	Drain Current-Single Pulsed	40	А				
PD	Total Dissipation @T _C =25°C	104	W				
Tj	Max. Operating Junction Temperature	150	°C				
T _{stg}	Storage Temperature	-55~150	°C				
THERMAL CHARACTERISTICS							
SYMBOL	PARAMETER	МАХ	UNIT				



Channel-to-case thermal resistance

Rth(ch-c)

°C/W

1.2

1



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; ID =0.25mA	600			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; ID =0.52mA	2.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; ID=7.8A			0.25	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} =20V; V _{DS} =0V			0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =600V; V _{GS} = 0V			1	μA
V _{SD}	Diode forward voltage	I _F =7.8A; V _{GS} = 0V			1.2	v

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